

NPN Epitaxial Silicon Transistor

BC546 / BC547 / BC548 / BC549 / BC550

Features

• Switching and Amplifier

• High-Voltage: BC546, V_{CEO} = 65 V

• Low-Noise: BC549, BC550

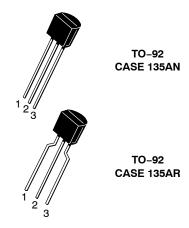
• Complement to BC556, BC557, BC558, BC559, and BC560

• These are Pb-Free Devices

ABSOLUTE MAXIMUM RATINGS

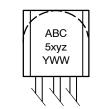
Parameter	Symbol	Value	Unit
Collector-Base Voltage BC546 BC547 / BC550 BC548 / BC549	V_{CBO}	80 50 30	>
Collector-Emitter Voltage BC546 BC547 / BC550 BC548 / BC549	V _{CEO}	65 45 30	V
Emitter-Base Voltage BC546 / BC547 BC548 / BC549 / BC550	V _{EBO}	6 5	V
Collector Current (DC)	I _C	100	mA
Collector Power Dissipation	P _C	500	mW
Junction Temperature	T _J	150	°C
Storage Temperature Range	T _{STG}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



1. Collector 2. Base 3. Emitter

MARKING DIAGRAM



BC5xyz = Device Code x = 4 or 5

> y = 6, 7, 8, 9 or 0 z = A, B, C

A = Assembly Location

Y = Year WW = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 4.

1

BC546 / BC547 / BC548 / BC549 / BC550

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Symbol		Parameter	Test Condition	Min.	Тур.	Max.	Units	
I _{CBO}	Collector Cut-o	off Current	$V_{CB} = 30 \text{ V}, I_{E} = 0$			15	nA	
h _{FE}	DC Current Gain		$V_{CE} = 5 \text{ V}, I_{C} = 2 \text{ mA}$	110		800		
V _{CE} (sat)	Collector-Emit	ter Saturation Voltage	I _C = 10 mA, I _B = 0.5 mA		90	250	mV	
			I _C = 100 mA, I _B = 5 mA		250	600		
V _{BE} (sat)	Base-Emitter Saturation Voltage		I _C = 10 mA, I _B = 0.5 mA		700		mV	
			$I_C = 100 \text{ mA}, I_B = 5 \text{ mA}$		900			
V _{BE} (on)	Base-Emitter On Voltage Current Gain Bandwidth Product		V _{CE} = 5 V, I _C = 2 mA	580	660	700	mV	
			V _{CE} = 5 V, I _C = 10 mA			720		
f _T			$V_{CE} = 5 \text{ V, } I_{C} = 10 \text{ mA,}$ f = 100 MHz		300		MHz	
C _{ob}	Output Capacit	ance	V _{CB} = 10 V, I _E = 0, f = 1 MHz		3.5	6.0	pF	
C _{ib}	Input Capacitance		V _{EB} = 0.5 V, I _C = 0, f = 1 MHz		9		pF	
NF	NF Noise Figure BC546 / BC547 / BC548 BC549 / BC550 BC549	BC546 / BC547 / BC548	$V_{CE} = 5 \text{ V}, I_{C} = 200 \mu\text{A},$		2.0	10.0	dB	
		BC549 / BC550 $f = 1 \text{ kHz}, H_G = 2 \text{ k}\Omega$	$f = 1 \text{ kHz}, R_G = 2 \text{ k}\Omega$		1.2	4.0		
		$V_{CE} = 5 \text{ V}, I_{C} = 200 \mu\text{A},$		1.4	4.0			
		BC550	$R_G = 2 \text{ k}\Omega, f = 30 \text{ to } 15000 \text{ MHz}$		1.4	3.0		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

hFE CLASSIFICATION

Classification	Α	В	С
h _{FE}	110 ~ 220	200 ~ 450	420 ~ 800

BC546 / BC547 / BC548 / BC549 / BC550

TYPICAL PERFORMANCE CHARACTERISTICS

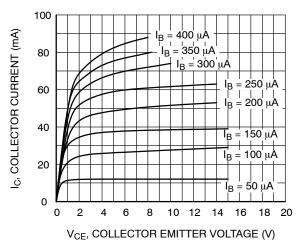


Figure 1. Static Characteristic

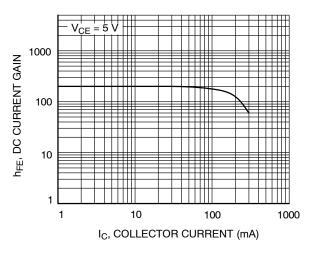


Figure 3. DC Current Gain

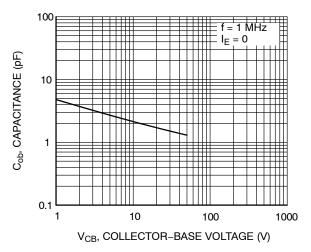


Figure 5. Output Capacitance

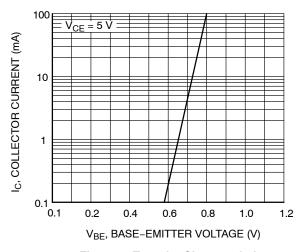


Figure 2. Transfer Characteristics

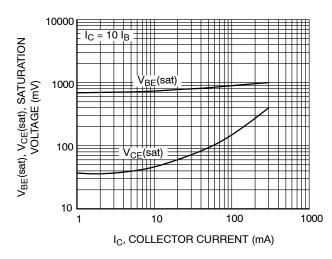


Figure 4. Base–Emitter Saturation Voltage and Collector–Emitter Saturation Voltage

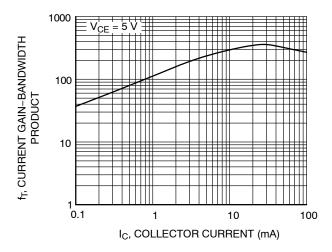


Figure 6. Current Gain Bandwidth Product

BC546 / BC547 / BC548 / BC549 / BC550

ORDERING INFORMATION

Part Number	Marking	Package	Packing Method [†]
BC546ABU	BC546A	TO-92-3 (Pb-Free)	10000 / Bulk Bag
BC546CTA	BC546C	TO-92-3 (Pb-Free)	2000 / Ammo Pack
BC547B	BC547B	TO-92-3 (Pb-Free)	10000 / Bulk Bag
BC547BBU	BC547B	TO-92-3 (Pb-Free)	10000 / Bulk Bag
BC547BTF	BC547B	TO-92-3 (Pb-Free)	2000 / Tape & Reel
BC547CBU	BC547C	TO-92-3 (Pb-Free)	10000 / Bulk Bag
BC547CTA	BC547C	TO-92-3 (Pb-Free)	2000 / Ammo Pack
BC549BTA	BC549B	TO-92-3 (Pb-Free)	2000 / Ammo Pack
BC549CTA	BC549C	TO-92-3 (Pb-Free)	2000 / Ammo Pack
BC550CBU	BC550C	TO-92-3 (Pb-Free)	10000 / Bulk Bag

DISCONTINUED (Note 1)

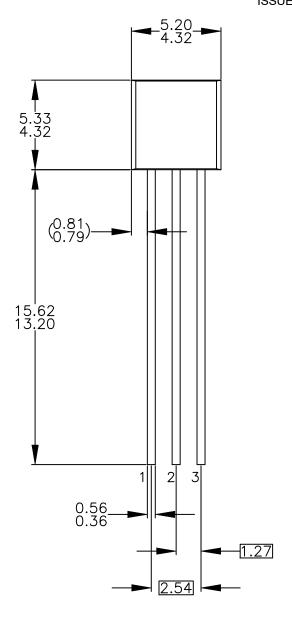
BC546ATA	BC546A	TO-92-3 (Pb-Free)	2000 / Ammo Pack
BC546BTA	BC546B	TO-92-3 (Pb-Free)	2000 / Ammo Pack
BC546BTF	BC546B	TO-92-3 (Pb-Free)	2000 / Tape & Reel
BC547ATA	BC547A	TO-92-3 (Pb-Free)	2000 / Ammo Pack
BC547BTA	BC547B	TO-92-3 (Pb-Free)	2000 / Ammo Pack
BC547CTFR	BC547C	TO-92-3 (Pb-Free)	2000 / Tape & Reel
BC548BU	BC548	TO-92-3 (Pb-Free)	10000 / Bulk Bag
BC548BTA	BC548B	TO-92-3 (Pb-Free)	2000 / Ammo Pack
BC548CTA	BC548C	TO-92-3 (Pb-Free)	2000 / Ammo Pack
BC549BTF	BC549B	TO-92-3 (Pb-Free)	2000 / Tape & Reel
BC550CTA	BC550C	TO-92-3 (Pb-Free)	2000 / Ammo Pack

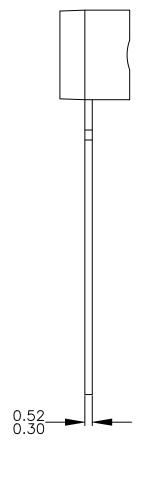
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DISCONTINUED: These devices are not recommended for new design. Please contact your onsemi representative for information. The
most current information on these devices may be available on www.onsemi.com.

TO-92 3 4.825x4.76 CASE 135AN ISSUE O

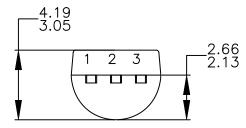
DATE 31 JUL 2016





NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS. A)
- ALL DIMENSIONS ARE IN MILLIMETERS.
 DRAWING CONFORMS TO ASME Y14.5M—2009.



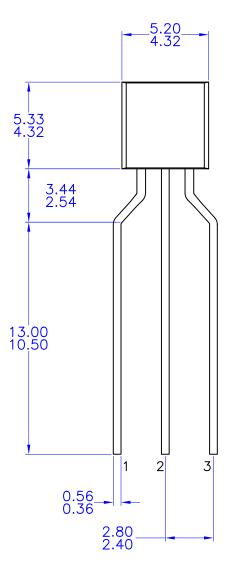
DOCUMENT NUMBER:	98AON13880G	Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	TO-92 3 4.825X4.76		PAGE 1 OF 1

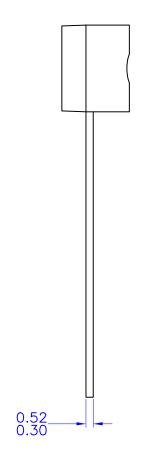
ON Semiconductor and III are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

TO-92 3 4.83x4.76 LEADFORMED

CASE 135AR ISSUE O

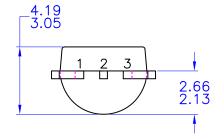
DATE 30 SEP 2016





NOTES: UNLESS OTHERWISE SPECIFIED

- A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DRAWING CONFORMS TO ASME Y14.5M-1994



DOCUMENT NUMBER:	98AON13879G	Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	N: TO-92 3 4.83X4.76 LEADFORMED		PAGE 1 OF 1

ON Semiconductor and at a trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales